

# R1LV0816ASB – 5SI, 7SI

8Mb Advanced LPSRAM (512k word x 16bit)

REJ03C0387-0100

Rev.1.00

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## Description

The R1LV0816ASB is a family of low voltage 8-Mbit static RAMs organized as 524,288-words by 16-bit, fabricated by Renesas's high-performance 0.15um CMOS and TFT technologies.

The R1LV0816ASB is suitable for memory applications where a simple interfacing, battery operating and battery backup are the important design objectives.

The R1LV0816ASB is packaged in a 44pin thin small outline mount device [11.76mm×18.41mm 44-pin plastic TSOP (II)]. It gives the best solution for a compaction of mounting area as well as flexibility of wiring pattern of printed circuit boards.

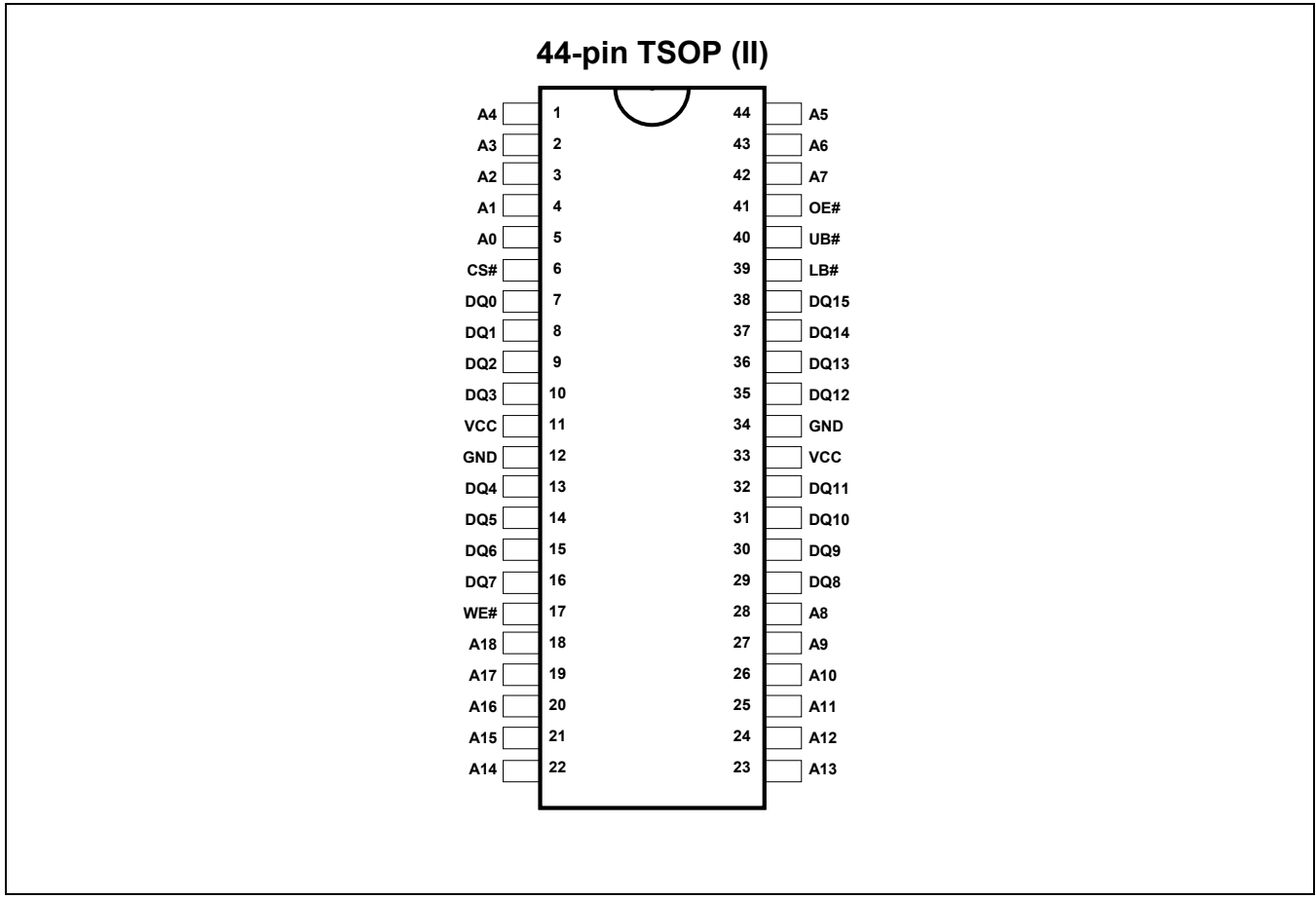
## Features

- Single 2.4-3.6V power supply
- Small stand-by current: 1.2μA (Vcc=3.0V, typ.)
- No clocks, No refresh
- All inputs and outputs are TTL compatible
- Easy memory expansion by CS#, LB# and UB#
- Common Data I/O
- Three-state outputs: OR-tie capability
- OE# prevents data contention in the I/O bus
- Operation temperature: -40 ~ +85°C

## Ordering information

Type No.	Power supply	Access time	Temperature Range	Package
R1LV0816ASB-5SI	2.7V to 3.6V	55 ns	-40 ~ +85°C	11.76mm×18.41mm 44-pin plastic TSOP (II) (normal-bend type) (44P3F)
	2.4V to 2.7V	70 ns		
R1LV0816ASB-7SI	2.4V to 3.6V	70 ns		

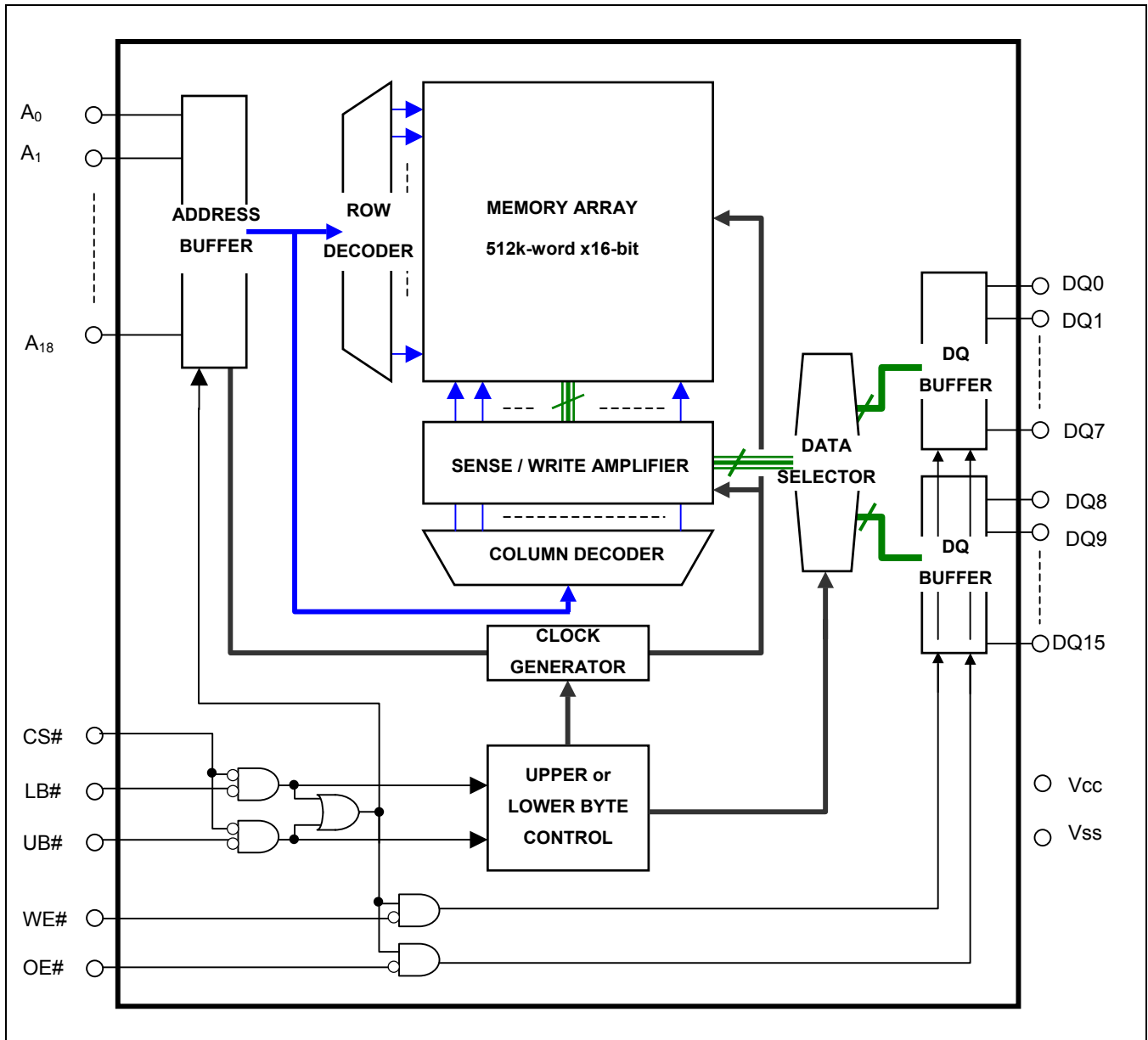
Pin Arrangement



## Pin Description

Pin name	Function
Vcc	Power supply
Vss	Ground
A0 to A18	Address input (word mode)
DQ0 to DQ15	Data input/output
CS#	Chip select
WE#	Write enable
OE#	Output enable
LB#	Lower byte enable
UB#	Upper byte enable

Block Diagram



## Operation Table

CS#	WE#	OE#	UB#	LB#	DQ0~7	DQ8~15	Operation
H	X	X	X	X	High-Z	High-Z	Stand-by
X	X	X	H	H	High-Z	High-Z	Stand-by
L	L	X	H	L	Din	High-Z	Write in lower byte
L	H	L	H	L	Dout	High-Z	Read in lower byte
L	L	X	L	H	High-Z	Din	Write in upper byte
L	H	L	L	H	High-Z	Dout	Read in upper byte
L	L	X	L	L	Din	Din	Word write
L	H	L	L	L	Dout	Dout	Word read
L	H	H	L	L	High-Z	High-Z	Output disable
L	H	H	L	H	High-Z	High-Z	Output disable
L	H	H	H	L	High-Z	High-Z	Output disable

Note 1. H:  $V_{IH}$  L:  $V_{IL}$  X:  $V_{IH}$  or  $V_{IL}$

## Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Power supply voltage relative to Vss	Vcc	-0.5 to +4.6	V
Terminal voltage on any pin relative to Vss	$V_T$	$-0.5^{*1}$ to $V_{cc}+0.3^{*2}$	V
Power dissipation	$P_T$	0.7	W
Operation temperature	Topr	-40 to +85	°C
Storage temperature range	Tstg	-65 to 150	°C
Storage temperature range under bias	Tbias	-40 to +85	°C

Note 1. -3.0V in case of AC (Pulse width  $\leq 30$ ns)

2. Maximum voltage is +4.6V

## Recommend Operating Conditions

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions	Note
Supply voltage	V <sub>CC</sub>	2.4	3.0	3.6	V	-	
	V <sub>SS</sub>	0	0	0	V	-	
Input high voltage	V <sub>IH</sub>	2.0	-	V <sub>CC</sub> +0.2	V	V <sub>CC</sub> =2.4V to 2.7V	
		2.2	-	V <sub>CC</sub> +0.2	V	V <sub>CC</sub> =2.7V to 3.6V	
Input low voltage	V <sub>IL</sub>	-0.2	-	0.4	V	V <sub>CC</sub> =2.4V to 2.7V	1
		-0.2	-	0.6	V	V <sub>CC</sub> =2.7V to 3.6V	1
Ambient temperature range	T <sub>a</sub>	-40	-	+85	°C	-	

Note 1. -3.0V in case of AC (Pulse width ≤30ns)

## DC Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions
Input leakage current	I <sub>LI</sub>	-	-	1	μA	V <sub>in</sub> = V <sub>SS</sub> to V <sub>CC</sub>
Output leakage current	I <sub>LO</sub>	-	-	1	μA	CS# = V <sub>IH</sub> or OE# = V <sub>IH</sub> or WE# = V <sub>IL</sub> or LB# = UB# = V <sub>IH</sub> , VI/O = V <sub>SS</sub> to V <sub>CC</sub>
Average operating current	I <sub>CC1</sub>	-	20 <sup>*1</sup>	35	mA	Min. cycle, duty = 100%, I <sub>I/O</sub> = 0mA CS# = V <sub>IL</sub> , Others = V <sub>IH</sub> /V <sub>IL</sub>
	I <sub>CC2</sub>	-	2 <sup>*1</sup>	5	mA	Cycle = 1□s, duty = 100%, I <sub>I/O</sub> = 0mA CS# ≤ 0.2V, V <sub>IH</sub> ≥ V <sub>CC</sub> -0.2V, V <sub>IL</sub> ≤ 0.2V
Standby current	I <sub>SB</sub>	-	-	1	mA	CS# = V <sub>IH</sub>
Standby current	I <sub>SB1</sub>	-	1.2 <sup>*1</sup>	4	μA	~+25°C V <sub>in</sub> ≥ 0V
		-	3 <sup>*2</sup>	6	μA	~+40°C (1) CS# ≥ V <sub>CC</sub> -0.2V or (2) LB# = UB# ≥ V <sub>CC</sub> -0.2V, CS# ≤ 0.2V,
		-	-	15	μA	~+70°C
		-	-	20	μA	~+85°C
Output high voltage	V <sub>OH</sub>	2.4	-	-	V	I <sub>OH</sub> = -1mA V <sub>CC</sub> ≥ 2.7V
	V <sub>OH2</sub>	2.0	-	-	V	I <sub>OH</sub> = -0.1mA
Output low voltage	V <sub>OL</sub>	-	-	0.4	V	I <sub>OL</sub> = 2mA V <sub>CC</sub> ≥ 2.7V
	V <sub>OL2</sub>	-	-	0.4	V	I <sub>OL</sub> = 0.1mA

Note 1. Typical parameter indicates the value for the center of distribution at 3.0V(T<sub>a</sub>=+25°C), and not 100% tested.

2. Typical parameter indicates the value for the center of distribution at 3.0V(T<sub>a</sub>=+40°C), and not 100% tested.

## Capacitance

(Ta =25°C, f =1MHz)

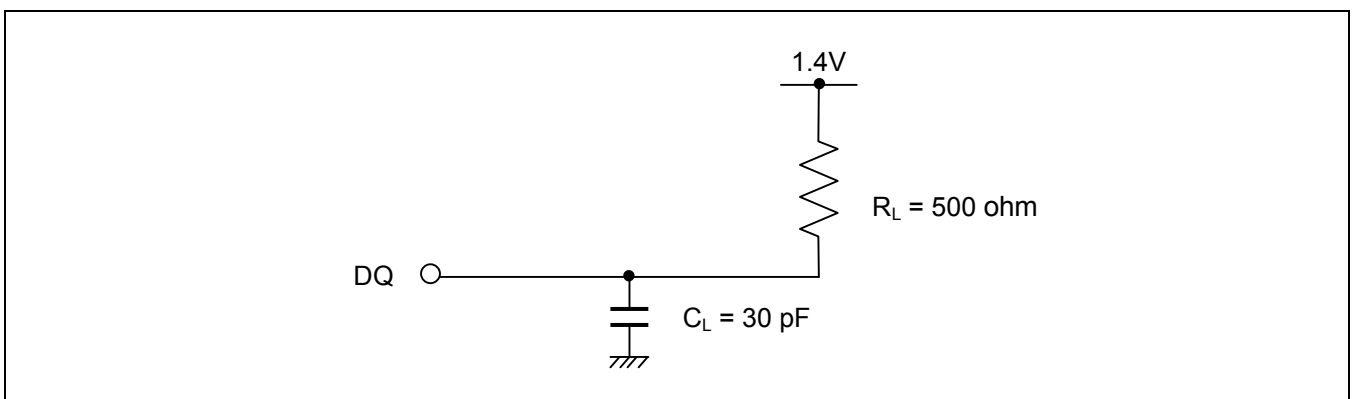
Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions	Note
Input capacitance	C <sub>in</sub>	-	-	10	pF	V <sub>in</sub> =0V	1
Input / output capacitance	C <sub>I/O</sub>	-	-	10	pF	V <sub>I/O</sub> =0V	1

Note 1. Typical parameter is sampled and not 100% tested.

## AC Characteristics

Test Conditions (V<sub>cc</sub> = 2.4V ~ 3.6V, Ta = -40 ~ +85°C)

- Input pulse levels: V<sub>IL</sub> = 0.4V, V<sub>IH</sub> = 2.4V (V<sub>cc</sub> = 2.7V ~ 3.6 V)  
V<sub>IL</sub> = 0.4V, V<sub>IH</sub> = 2.2V (V<sub>cc</sub> = 2.4V ~ 2.7 V)
- Input rise and fall times: 5ns
- Input and output timing reference level: 1.4V
- Output load: See figures (Including scope and jig)



## Read cycle

Parameter	Symbol	R1LV0816ASB-5SI (Note 0)		R1LV0816ASB-7SI		Unit	Note
		Min.	Max.	Min.	Max.		
Read cycle time	$t_{RC}$	55	-	70	-	ns	
Address access time	$t_{AA}$	-	55	-	70	ns	
Chip select access time	$t_{ACS}$	-	55	-	70	ns	
Output enable to output valid	$t_{OE}$	-	30	-	35	ns	
Output hold from address change	$t_{OH}$	10	-	10	-	ns	
LB#, UB# access time	$t_{BA}$	-	55	-	70	ns	
Chip select to output in low-Z	$t_{CLZ}$	10	-	10	-	ns	2,3
LB#, UB# enable to low-Z	$t_{BLZ}$	5	-	5	-	ns	2,3
Output enable to output in low-Z	$t_{OLZ}$	5	-	5	-	ns	2,3
Chip deselect to output in high-Z	$t_{CHZ}$	0	20	0	25	ns	1,2,3
LB#, UB# disable to high-Z	$t_{BHZ}$	0	20	0	25	ns	1,2,3
Output disable to output in high-Z	$t_{OHZ}$	0	20	0	25	ns	1,2,3



## Write Cycle

Parameter	Symbol	R1LV0816ASB-5SI (Note 0)		R1LV0816ASB-7SI		Unit	Note
		Min.	Max.	Min.	Max.		
Write cycle time	$t_{WC}$	55	-	70	-	ns	
Address valid to end of write	$t_{AW}$	50	-	65	-	ns	
Chip select to end of write	$t_{CW}$	50	-	65	-	ns	5
Write pulse width	$t_{WP}$	40	-	55	-	ns	4
LB#, UB# valid to end of write	$t_{BW}$	50	-	65	-	ns	
Address setup time	$t_{AS}$	0	-	0	-	ns	6
Write recovery time	$t_{WR}$	0	-	0	-	ns	7
Data to write time overlap	$t_{DW}$	25	-	35	-	ns	
Data hold from write time	$t_{DH}$	0	-	0	-	ns	
Output enable from end of write	$t_{OW}$	5	-	5	-	ns	2
Output disable to output in high-Z	$t_{OHZ}$	0	20	0	25	ns	1,2
Write to output in high-Z	$t_{WHZ}$	0	20	0	25	ns	1,2

Note 0. If Vcc is 2.4-2.7V, parameters of R1LV0816ASB-7SI (70ns) are applied.

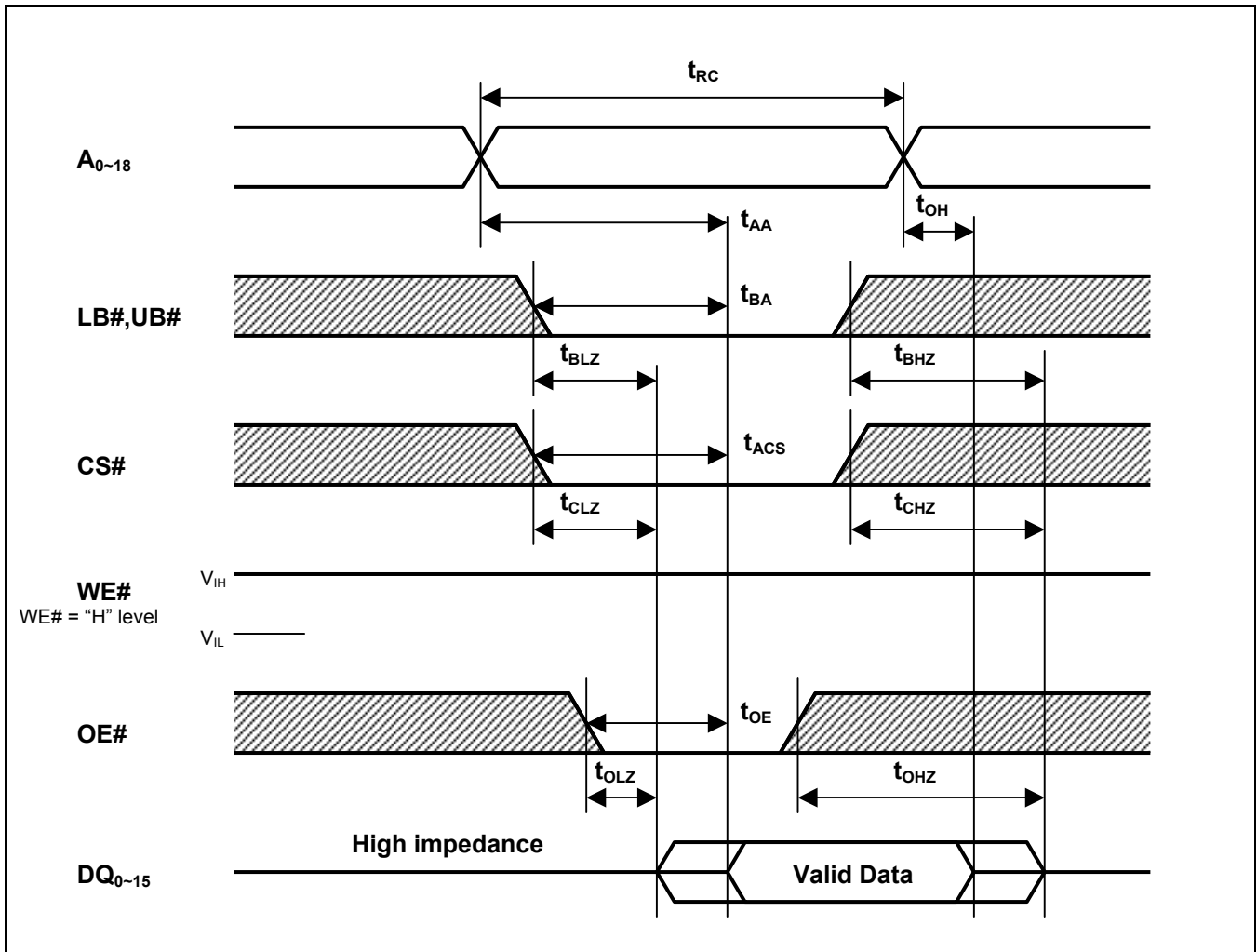
- $t_{CHZ}$ ,  $t_{OHZ}$ ,  $t_{WHZ}$  and  $t_{BHZ}$  are defined as the time at which the outputs achieve the open circuit conditions and are not referred to output voltage levels.
- Typical parameter is sampled and not 100% tested.
- At any given temperature and voltage condition,  $t_{HZ}$  max is less than  $t_{LZ}$  min both for given device and from device to device.
- A write occurs during the overlap of a low CS#, a low WE# and a low LB# or low UB#.
 

A write begins at the latest transitions among CS# going low, WE# going low and LB# going low or UB# going low.

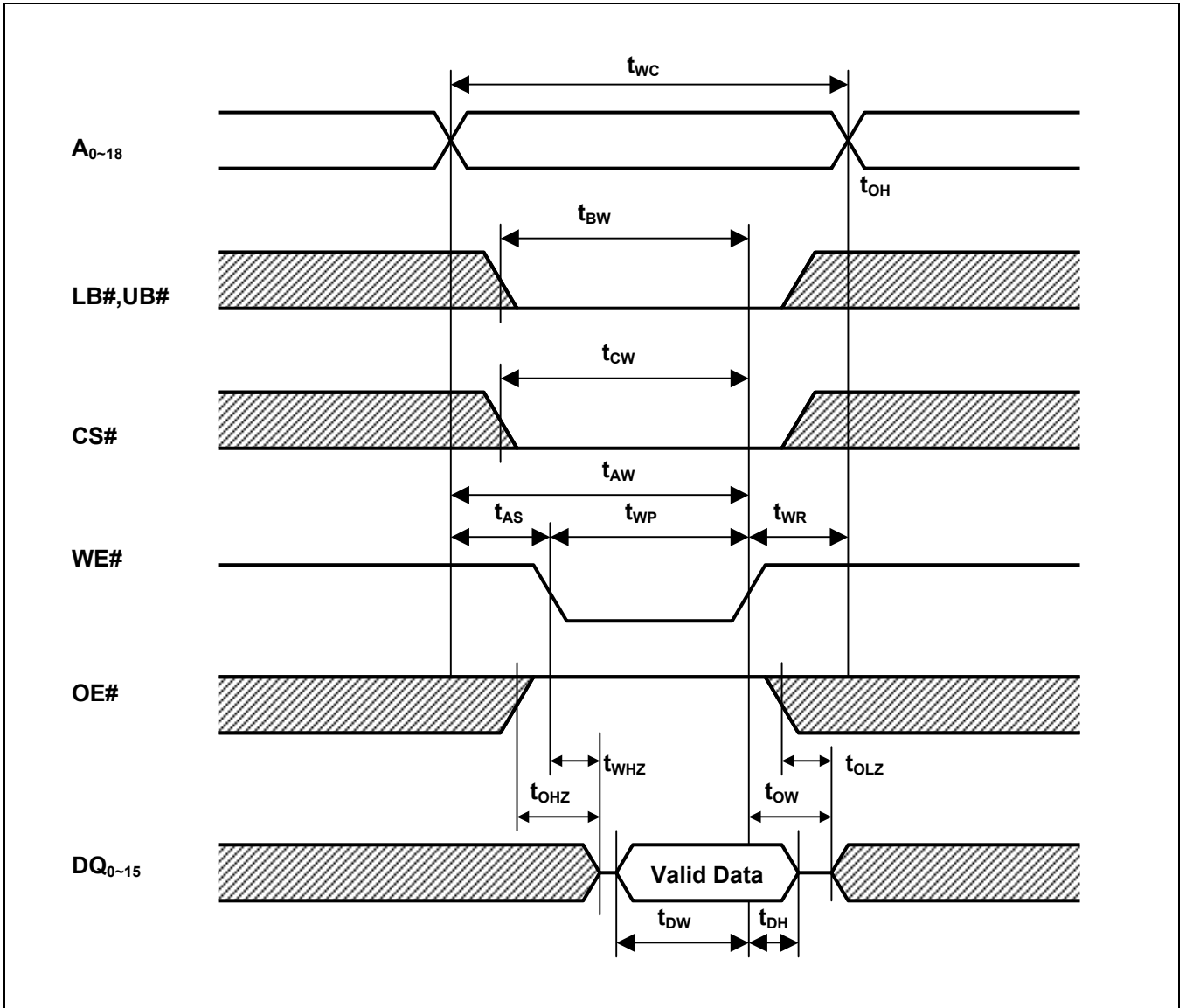
A write ends at the earliest transitions among CS# going high, WE# going high and LB# going high or UB# going high.  $t_{WP}$  is measured from the beginning of write to the end of write.
- $t_{CW}$  is measured from the later of CS# going low to the end of write.
- $t_{AS}$  is measured the address valid to the beginning of write.
- $t_{WR}$  is measured from the earliest of CS# or WE# going high to the end of write cycle.

Timing Waveforms

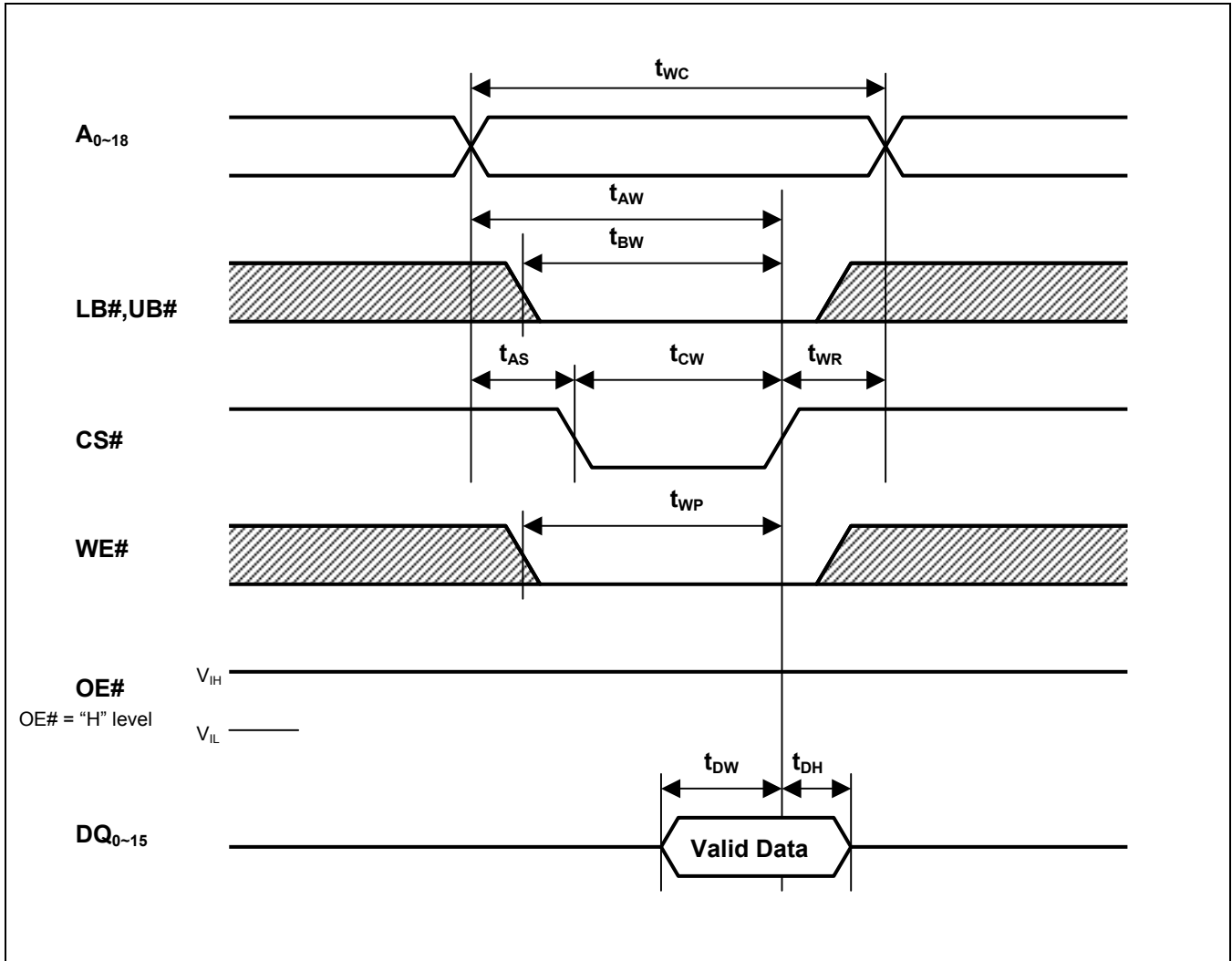
Read Cycle



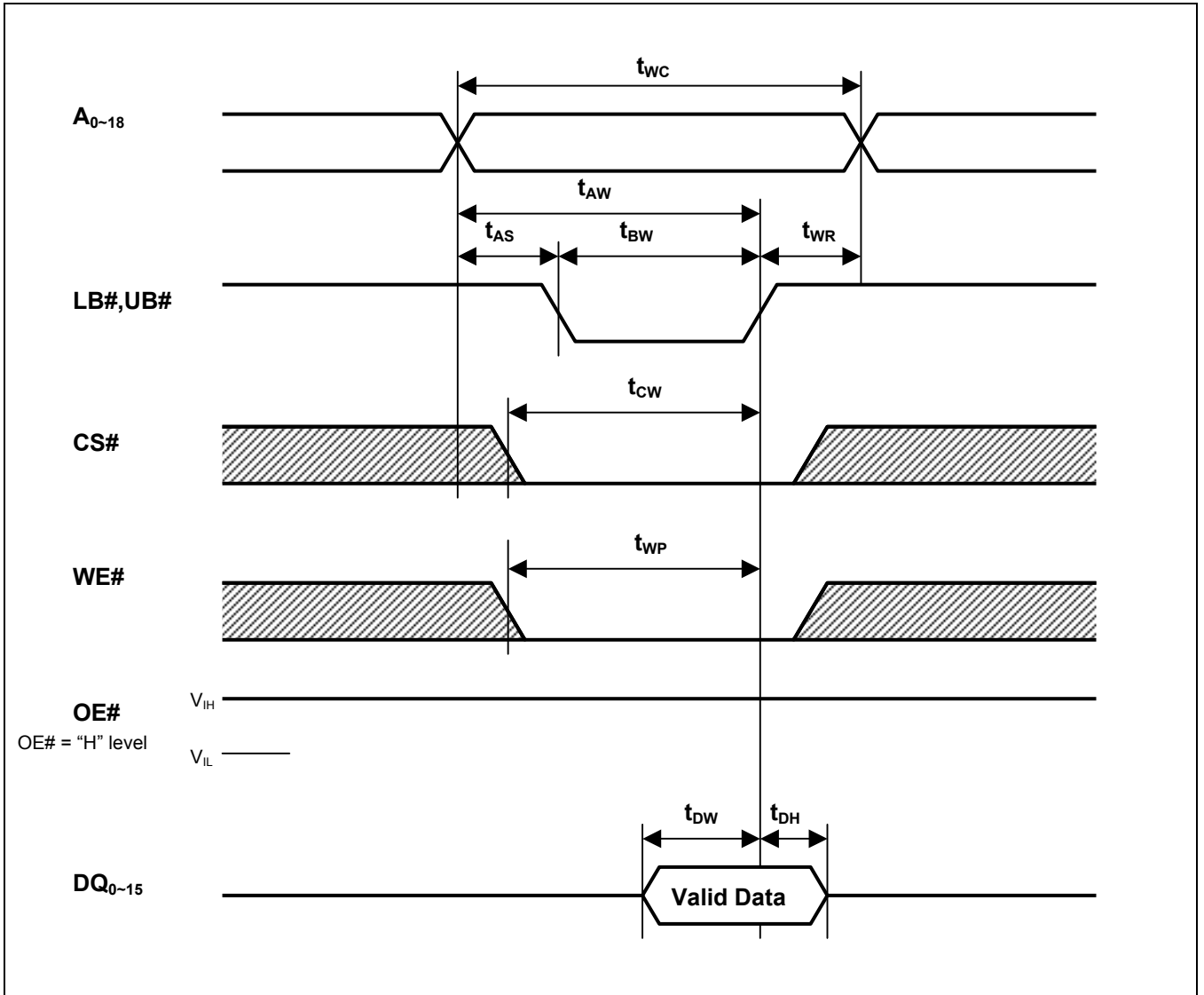
Write Cycle (1) (WE# CLOCK)



Write Cycle (2) (CS# CLOCK)



Write Cycle (3) (LB#, UB# CLOCK)



## Data Retention Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions <sup>*3</sup>	
$V_{CC}$ for data retention	$V_{DR}$	1.5	-	3.6	V	$V_{in} \geq 0V$ (1) $CS\# \geq V_{CC}-0.2V$ , (2) $LB\# = UB\# \geq V_{CC}-0.2V$ , $CS\# \leq 0.2V$ ,	
Data retention current	$I_{CCDR}$	-	1.2 <sup>*1</sup>	4	$\mu A$	$\sim +25^{\circ}C$	$V_{CC}=3.0V$ , $V_{in} \geq 0V$ (1) $CS\# \geq V_{CC}-0.2V$ or (2) $LB\# = UB\# \geq V_{CC}-0.2V$ , $CS\# \leq 0.2V$ ,
		-	3 <sup>*2</sup>	6	$\mu A$	$\sim +40^{\circ}C$	
		-	-	15	$\mu A$	$\sim +70^{\circ}C$	
		-	-	20	$\mu A$	$\sim +85^{\circ}C$	
Chip select to data retention time	$t_{CDR}$	0	-	-	ns	See retention waveform.	
Operation recovery time	$t_R$	5	-	-	ms		

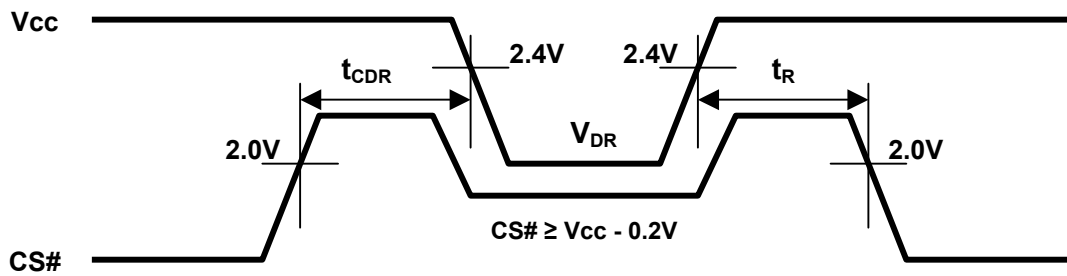
Note 1. Typical parameter indicates the value for the center of distribution at 3.0V( $T_a = +25^{\circ}C$ ), and not 100% tested.

2. Typical parameter indicates the value for the center of distribution at 3.0V( $T_a = +40^{\circ}C$ ), and not 100% tested.

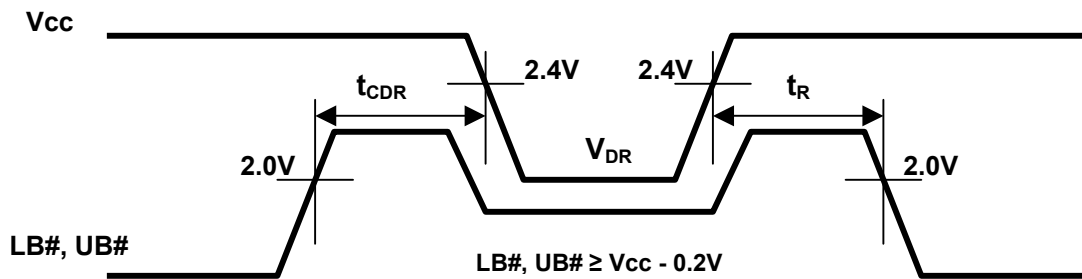
3.  $CS\#$  controls address buffer,  $WE\#$  buffer,  $OE\#$  buffer,  $LB\#$ ,  $UB\#$  buffer and  $Din$  buffer. If  $CS\#$  controls data retention mode,  $V_{in}$  levels (address,  $WE\#$ ,  $OE\#$ ,  $LB\#$ ,  $UB\#$ ,  $DQ$ ) can be in the high impedance state.

Data Retention Timing Waveforms

(1) CS# controlled



(2) LB#, UB# controlled



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April 1<sup>st</sup>, 2010  
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